2SD0946A, 2SD0946B

Silicon NPN epitaxial planar type darlington

For low-frequency amplification

■ Features

- Forward current transfer ratio h_{FE} is designed high, which is appropriate to the driver circuit of motors and printer hammer.
- A shunt resistor is omitted from the driver.

■ Absolute Maximum Ratings T_a = 25°C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SD0946A	V _{CBO}	60	V
(Emitter open)	2SD0946B		100	
Collector-emitter voltage	2SD0946A	V _{CEO}	50	V
(Base open)	2SD0946B		80	
Emitter-base voltage (Col	V _{EBO}	5	V	
Collector current	I_{C}	1	A	
Peak collector current	I_{CP}	1.5	A	
Collector power dissipation	P _C	1.2	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Package

Code

TO-126B-A1

Pin Name

1: Emitter

2: Collector

3: Base

■ Internal Connection

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

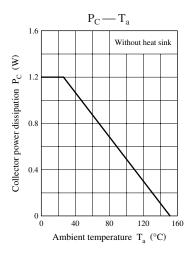
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage	2SD0946A	V _{CBO}	$I_{\rm C} = 100 \mu \text{A}, I_{\rm E} = 0$	60	~O()		V
(Emitter open)	2SD0946B		die die gestille	100	59		
Collector-emitter voltage	2SD0946A	V _{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	50			V
(Base open)	2SD0946B		9/31 8/13 . O . C	80			
Emitter-base voltage (Collector open)		V_{EBO}	$I_E = 100 \ \mu A, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)		I_{CBO}	$V_{CB} = 25 \text{ V}, I_{E} = 0$			0.1	μΑ
Emitter-base cutoff current (Collector open)		I_{EBO}	$V_{EB} = 4 \text{ V}, I_{C} = 0$			0.1	μΑ
Forward current transfer ratio *1, 2		h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ A}$	4000		40 000	_
Collector-emitter saturation voltage *1		V _{CE(sat)}	$I_C = 1 \text{ A}, I_B = 1 \text{ mA}$			1.8	V
Base-emitter saturation voltage *1		V _{BE(sat)}	$I_{\rm C} = 1 \text{ A}, I_{\rm B} = 1 \text{ mA}$			2.2	V
Transition frequency		f_T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

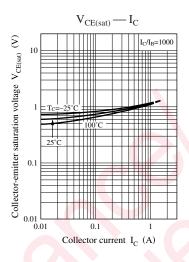
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

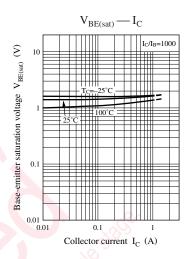
2. *1: Pulse measurement

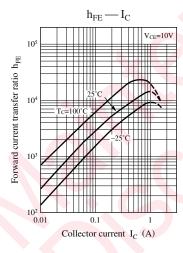
*2: Rank classification

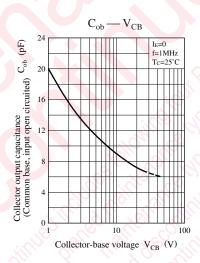
Rank	Q	R	S	
h_{FE}	4000 to 10000	8 000 to 20 000	16 000 to 40 000	



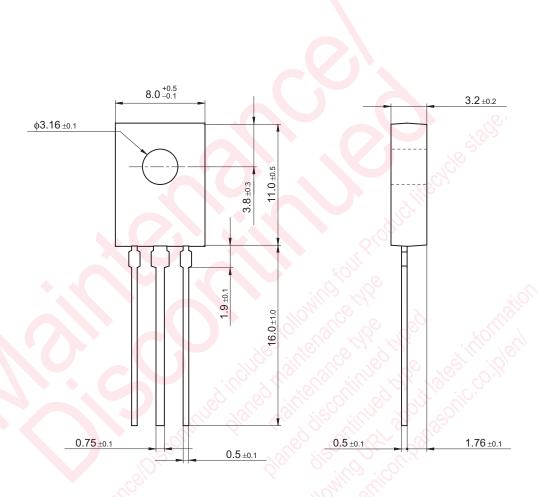


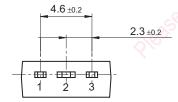






TO-126B-A1 Unit: mm





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